Electrochemistry of Atomically Thin Metallic Wires

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As materials shrink to the nanometer scales, various quantum phenomena become important. One interesting example is conductance quantization in metallic nanowires, which occurs in atomically thin metallic wires. We have studied double layer charging and electrochemically induced molecular adsorption effects on the conductance quantization of the metallic wires. In order to study the double layer charging effect, we measured the change in the conductance quantized at various quantum steps by modulating the electrochemical potential. The induced change in the conductance is 5at higher steps as the wires become thicker. We attribute the observed changes to the double layer charging effect. In the presence of molecular adsorption, the conductance drops to fractional values. The conductance changes correlate with the binding strength of the molecules to the metal wires. This observation suggests the possibility of chemical sensor applications based on the conductance changes in the nanowires, but the mechanism of the conductance changes is not yet well understood. One possible mechanism is the scattering of conduction electrons by the adsorbates, which reduces the conductance. This theory explains naturally the decreases in the conductance but it fails to explain other experimental facts. For example, the mechanical stability of the nanowires is strongly dependent on molecular adsorption. We have studied the mechanical stability by pulling a nanowire with a STM and found that the length over which the nanowire can be pulled before breaking is much longer in the presence of molecular adsorption. So it is clear that the binding of a molecule onto an atomically thin metal wire affects the mechanical properties of the wire.